


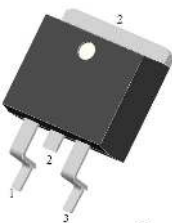
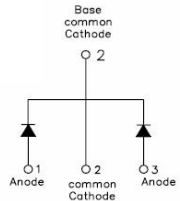
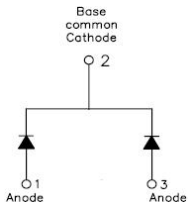
ST3060C/STB3060C SCHOTTKY RECTIFIER

Applications

- Switching power supply
- Converters
- Free-Wheeling diodes
- Reverse battery protection

Features

- 150 °C T_J operation
- Center tap configuration
- Ultralow forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- High frequency operation
- Trench MOS Schottky technology
- This is a Pb – Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

ST3060C	STB3060C
	
 <p>Base common Cathode</p> <p>Anode 1, common Cathode 2, Anode 3</p>	 <p>Base common Cathode</p> <p>Anode 1, common Cathode 2, Anode 3</p>
TO-220AB	D ² PAK

Maximum Ratings:

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{VRWM} V _R	-	60	V
Average Rectified Forward Current	I _{F(AV)}	50% duty cycle @T _c =120°C, rectangular wave form	15(Per Leg) 30(Per Device)	A
Peak One Cycle Non-Repetitive Surge Current(Per Leg)	I _{FSM}	8.3ms, Half Sine pulse, T _J = 25°C	170	A

Electrical Characteristics:

Characteristics	Symbol	Condition	Typ.	Max.	Units
Forward Voltage Drop(Per Leg)*	V _{F1}	@ 5A, Pulse, T _J = 25°C	0.42	-	V
		@ 7.5A, Pulse, T _J = 25°C	0.48	-	
@ 15A, Pulse, T _J = 25°C		0.59	0.70		
	V _{F2}	@ 5A, Pulse, T _J = 125°C	0.35	-	V
		@ 7.5A, Pulse, T _J = 125°C	0.41	-	
		@ 15A, Pulse, T _J = 125°C	0.55	0.65	
Reverse Current(Per Leg)*	I _{R1}	@V _R = rated V _R , T _J = 25°C	0.03	1.2	mA
	I _{R2}	@V _R = rated V _R , T _J = 125°C	14	45	mA
Junction Capacitance	C _T	@V _R = 5V, T _C = 25 °C f _{SIG} = 1MHz	712	-	pF

* Pulse width < 300 μs, duty cycle < 2%

Thermal-Mechanical Specifications:

Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	T _J	-	-55 to +150	°C
Storage Temperature	T _{stg}	-	-55 to +150	°C
Typical Thermal Resistance Junction to Case(Per Leg)	R _{θJC}	DC operation	2.2	°C/W

Ratings and Characteristics Curves

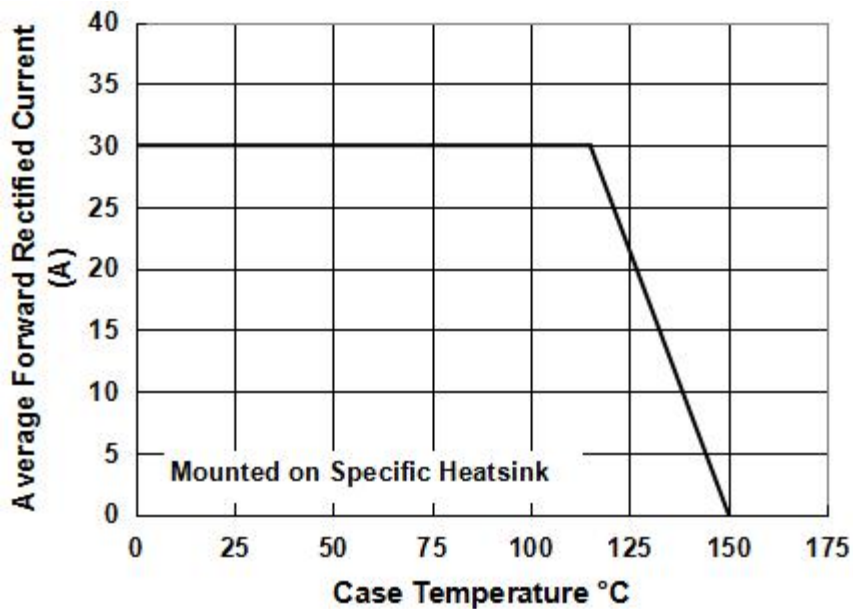
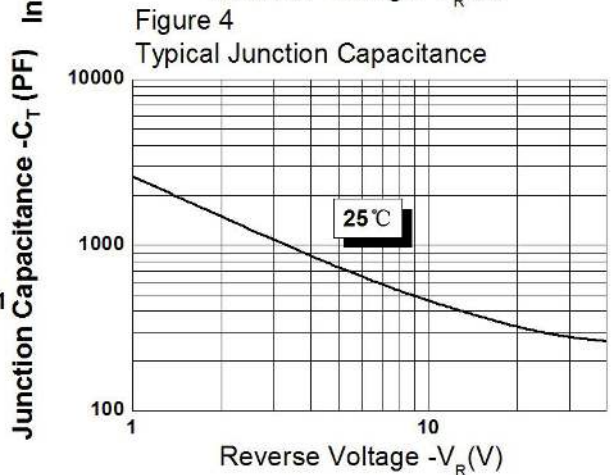
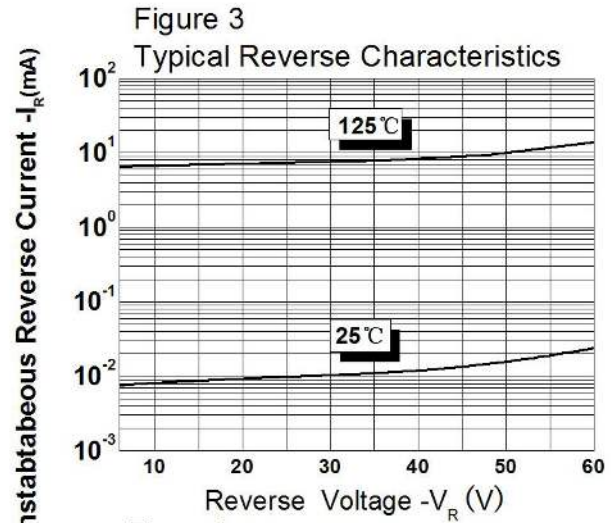
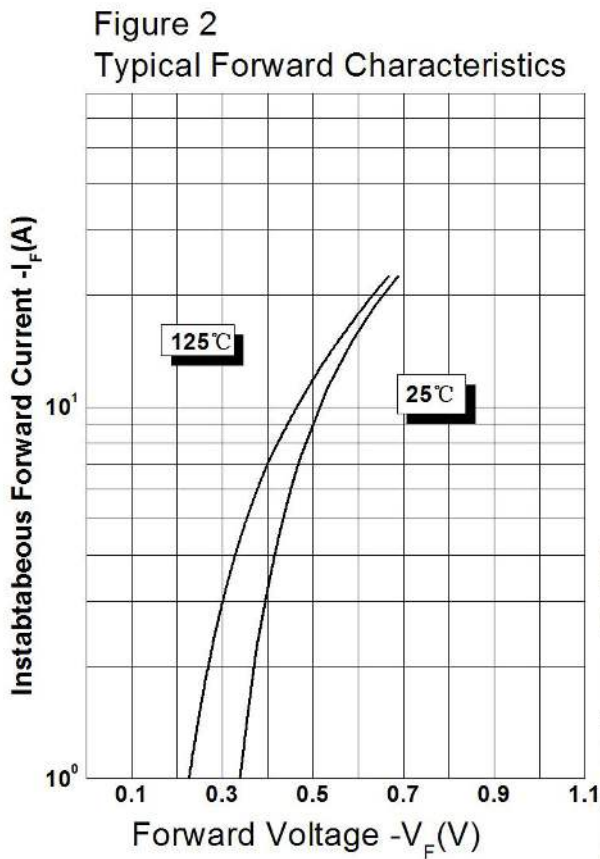


Figure 1. Maximum Forward Current Derating Curve

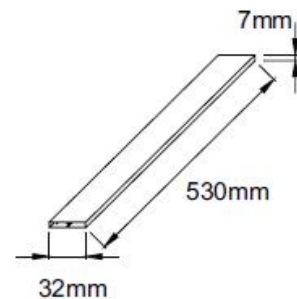


Tube Specification

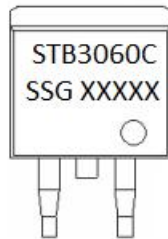
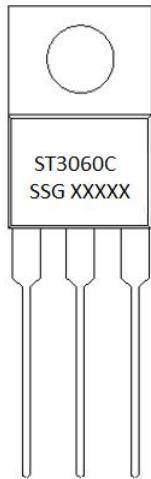
Device	Package	Weight	Shipping
ST3060C	TO-220AB	2.0	50pcs / tube
STB3060C	D ² PAK	1.85	800pcs / reel

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

Tube Specification(TO-220AB)



Marking Diagram

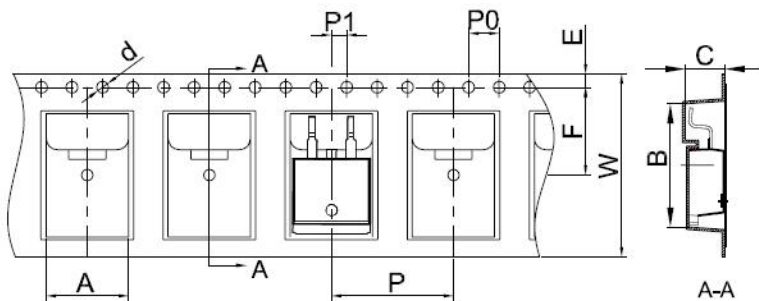


Where XXXXX is YYWWL

ST = Device Type
 B = Package type
 30 = Forward Current (30A)
 60 = Reverse Voltage (60V)
 C = Configuration
 SSG = SSG
 YY = Year
 WW = Week
 L = Lot Number

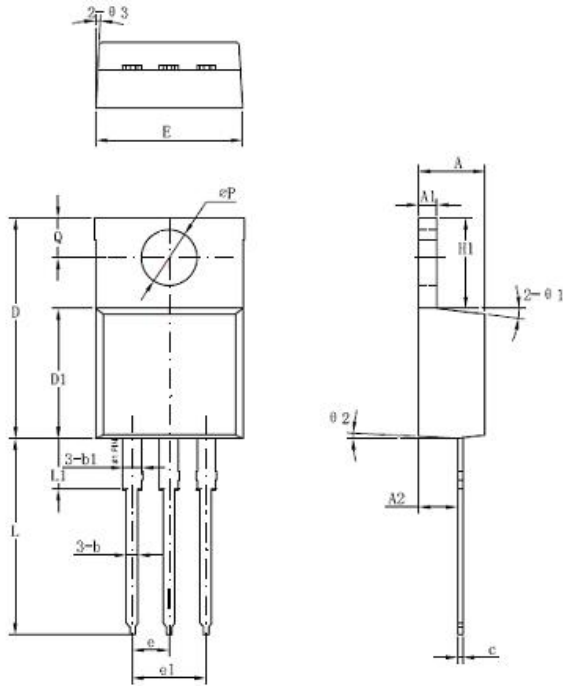
Cautions: Molding resin
 Epoxy resin UL:94V-0

Carrier Tape Specification D2PAK



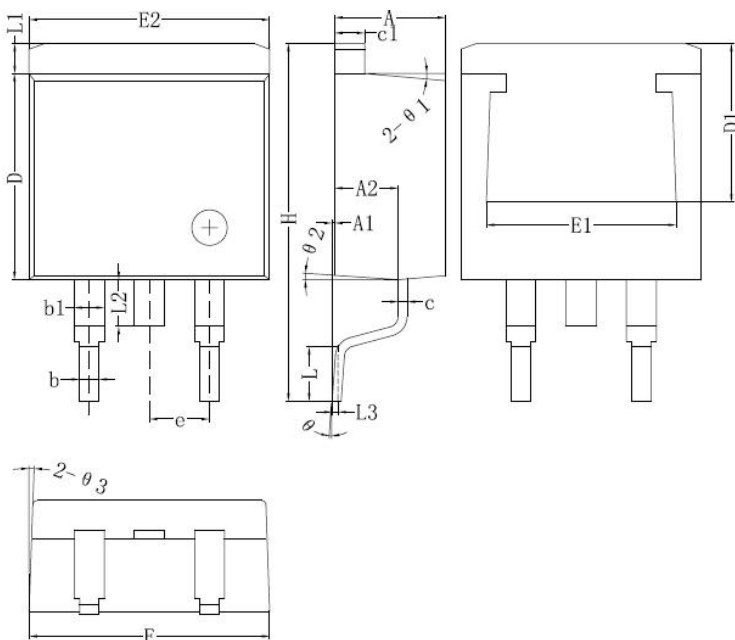
SYMBOL	Millimeters	
	Min.	Max.
A	10.70	10.90
B	16.03	16.23
C	5.11	5.31
d	1.45	1.65
E	1.65	1.85
F	11.40	11.60
P0	3.90	4.10
P	15.90	16.10
P1	1.90	2.10
W	23.90	24.30

Mechanical Dimensions TO-220AB



Symbol	Dimensions in millimeters		
	Min	Typical	Max
A	3.56	-	4.83
A1	0.51	-	1.4
A2	2.03	-	2.92
b	0.38	-	1.02
b1	1.14	-	1.78
c	0.31	-	0.61
D	14.22	-	16.51
D1	8.38	-	9.42
E	9.65	-	10.67
e	-	2.54	-
e1	-	5.08	-
H1	5.84	-	6.86
L	12.7	-	14.73
L1	-	-	6.35
ΦP	-	3.56	-
Q	2.54	-	3.43

Mechanical Dimensions D²PAK



Symbol	Dimensions in millimeters	
	Min.	Max.
A	4.06	4.83
A1	0	0.26
b	0.51	0.99
b1	1.14	1.78
c	0.31	0.74
c1	1.14	1.65
D	8.38	9.65
D1	6.4	
E1	6.22	
E2	9.65	10.67
e	2.54BSC	
H	14.6	15.88
L	1.78	2.8
L1	-	1.68
L2	-	2.2
L3	0.255BSC	
Φ	0	8°

Technical Data
Data Sheet N1423, Rev. A



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